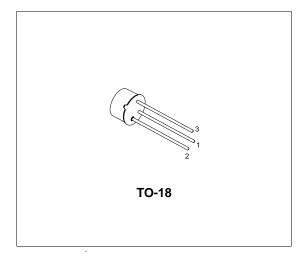


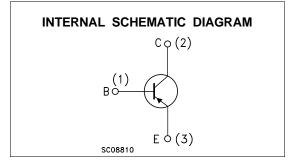
BC107 BC107B

LOW NOISE GENERAL PURPOSE AUDIO AMPLIFIERS

DESCRIPTION

The BC107 and BC107B are silicon Planar Epitaxial NPN transistors in TO-18 metal case. They are suitable for use in driver stages, low noise input stages and signal processing circuits of television reveivers. The PNP complementary types are BC177 and BC177B respectively.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vсво	Collector-Base Voltage $(I_E = 0)$	50	V
Vceo	Collector-Emitter Voltage ($I_B = 0$)	45	V
V _{EBO}	Emitter-Base Voltage $(I_C = 0)$	6	V
lc	Collector Current	100	mA
P _{tot}	Total Dissipation at $T_{amb} \le 25$ °C at $T_C \le 25$ °C	0.3 0.75	W W
T _{stg}	Storage Temperature	-55 to 175	°C
Tj	Max. Operating Junction Temperature	175	°C

THERMAL DATA

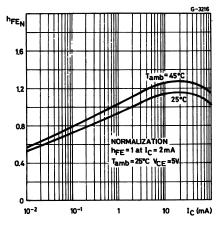
R _{thj-case}	Thermal Resistance Junction-Case	Max	200	°C/W
$R_{thj-amb}$	Thermal Resistance Junction-Ambient	Max	500	°C/W

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

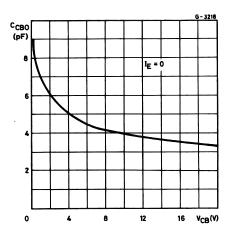
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{СВО}	Collector Cut-off Current (I _E = 0)	$V_{CB} = 40 V$ $V_{CB} = 40 V$ $T_{C} = 150 \ ^{\circ}C$			15 15	nΑ μΑ
V _(BR) CBO	Collector-Base Breakdown Voltage (I _E = 0)	Ic = 10 μA	50			V
$V_{(BR)CEO^*}$	Collector-Emitter Breakdown Voltage (I _B = 0)	I _C = 10 mA	45			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage (I _C = 0)	I _E = 10 μA	6			V
$V_{CE(sat)^*}$	Collector-Emitter Saturation Voltage	$ I_{C} = 10 \text{ mA} \qquad I_{B} = 0.5 \text{ mA} \\ I_{C} = 100 \text{ mA} \qquad I_{B} = 5 \text{ mA} $		70 200	250 600	mV mV
$V_{BE(sat)^*}$	Base-Emitter Saturation Voltage	$ I_{C} = 10 \text{ mA} \qquad I_{B} = 0.5 \text{ mA} \\ I_{C} = 100 \text{ mA} \qquad I_{B} = 5 \text{ mA} $		750 950		mV mV
$V_{BE(on)}*$	Base-Emitter On Voltage		550	650 700	700 770	mV mV
h _{FE} *	DC Current Gain		110 200 40	120 150	450 450	
h _{fe} *	Small Signal Current Gain	$\label{eq:CE} \begin{array}{ll} Ic = 2 \mbox{ mA} & V_{CE} = 5 \mbox{ V} \mbox{ f} = 1 \mbox{ KHz} \\ for \mbox{ BC107} \\ for \mbox{ BC107B} \\ Ic = 10 \mbox{ mA} \mbox{ V}_{CE} = 10 \mbox{ V} \mbox{ f} = 100 \mbox{ MHz} \end{array}$		250 300 2		
Ссво	Collector-Base Capacitance	$I_E = 0$ $V_{CB} = 10$ V $f = 1$ MHz		4	6	pF
Сево	Emitter-Base Capacitance	$I_C = 0$ $V_{EB} = 0.5$ V $f = 1$ MHz		12		pF
NF	Noise Figure	$ I_{C} = 0.2 \text{ mA} V_{CE} = 5 \text{ V} $ $ f = 1 \text{KHz} R_{g} = 2 \text{K} \Omega \text{B} = 200 \text{Hz} $		2	10	dB
h _{ie}	Input Impedance	$ I_{C} = 2 \ mA \qquad V_{CE} = 5 \ V f = 1 \ KHz $ for BC107 for BC107B		4 4.8		ΚΩ ΚΩ
h _{re}	Reverse Voltage Ratio	$ I_{C} = 2 \ mA \qquad V_{CE} = 5 \ V f = 1 \ KHz $ for BC107 for BC107B		2.2 2.7		10 ⁻⁴ 10 ⁻⁴
h _{oe}	Output Admittance	I _C = 2 mA V _{CE} = 5 V f = 1KHz for BC107 for BC107B		30 26		μS μS

* Pulsed: Pulse duration = $300 \ \mu$ s, duty cycle $\leq 1 \ \%$

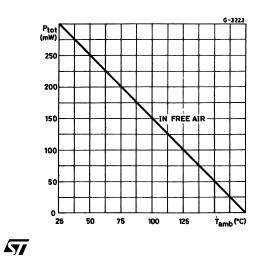
DC Normalized Current Gain.



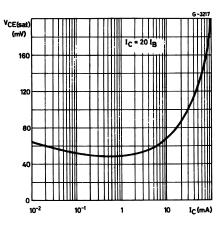
Collector-Base Capacitance



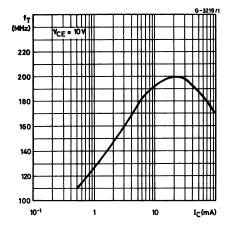
Power Rating Chart



Collector-Emitter Saturation Voltage

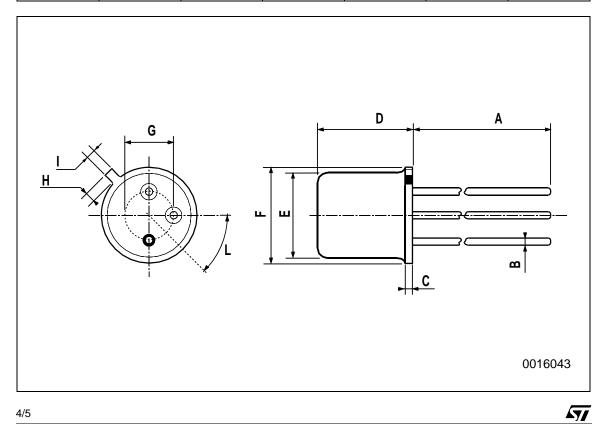


Transition Frequency



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TO-18 MECHANICAL DATA						
DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А		12.7			0.500	
В			0.49			0.019
D			5.3			0.208
E			4.9			0.193
F			5.8			0.228
G	2.54			0.100		
Н			1.2			0.047
I			1.16			0.045
L	45 [°]			45 [°]		



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